MOSFETs Silicon N-channel MOS (U-MOSVII)

TPN2R203NC

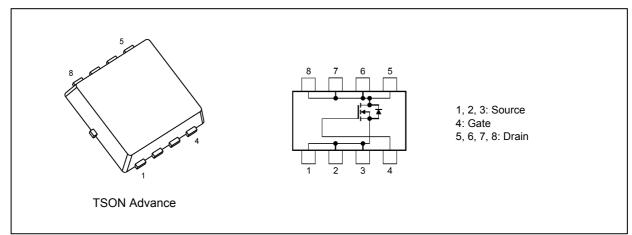
1. Applications

Power Management Switches

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)}$ = 1.8 m Ω (typ.) (V_{GS} = 10 V)
- (2) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (3) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_{D} = 0.5 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25$ °C unless otherwise specified)

Characteris	tics		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	30	V
Gate-source voltage	·		V _{GSS}	±20	V
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	Ι _D	100	A
Drain current (DC)	(T _c = 25 °C)	(Note 1)	Ι _D	45	A
Drain current (pulsed)	(t = 1 ms)	(Note 1)	I _{DP}	200	A
Power dissipation	(T _c = 25 °C)		PD	42	W
Power dissipation	(t = 10 s)	(Note 3)	PD	1.9	W
Power dissipation	(t = 10 s)	(Note 4)	PD	0.7	W
Single-pulse avalanche energy		(Note 5)	E _{AS}	126	mJ
Avalanche current			I _{AR}	45	A
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	(T _c = 25 °C)		R _{th(ch-c)}	2.97	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 3)	R _{th(ch-a)}	65.7	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 4)	R _{th(ch-a)}	178	°C/W

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Limited by silicon chip capability.

Note 3: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 4: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 5: V_DD = 24 V, T_ch = 25 °C (initial), L = 0.048 mH, I_{AR} = 45 A

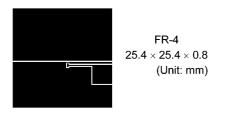


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

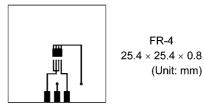


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

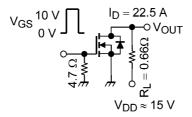
6.1. Static Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	10	μA
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	30	_	—	V
Drain-source breakdown voltage (Note 6)	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	15	_	_	V
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.5 mA	1.3	_	2.3	V
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 22.5 A	_	2.8	3.6	mΩ
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 22.5 A		1.8	2.2	mΩ

Note 6: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	_	2230	_	pF
Reverse transfer capacitance	C _{rss}		_	160	—	pF
Output capacitance	C _{oss}			650	_	pF
Switching time (rise time)	tr	See Fig. 6.2.1	_	9	_	ns
Switching time (turn-on time)	t _{on}		—	14	—	ns
Switching time (fall time)	t _f		_	24	_	ns
Switching time (turn-off time)	t _{off}			68	_	ns



Duty \leq 1%, $t_W =$ 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

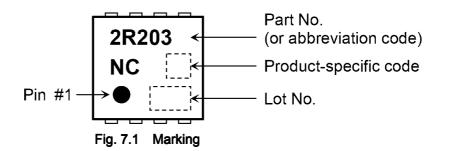
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	3	$V_{DD} \approx 15 \text{ V}, \text{ V}_{GS}$ = 10 V,	_	34	—	nC
Gate-source charge 1	Q _{gs1}	I _D = 45 A	_	8	—	nC
Gate-drain charge	Q _{gd}		_	6		nC

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

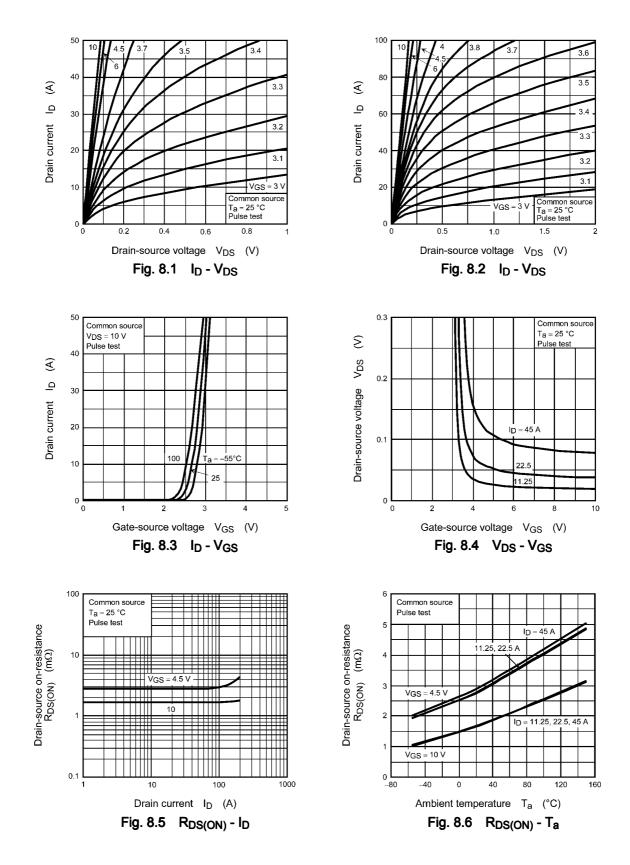
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (1 ms) (Note 7)	I _{DRP}	—	_	—	200	А
Diode forward voltage	V _{DSF}	I _{DR} = 45 A, V _{GS} = 0 V	_	_	-1.2	V

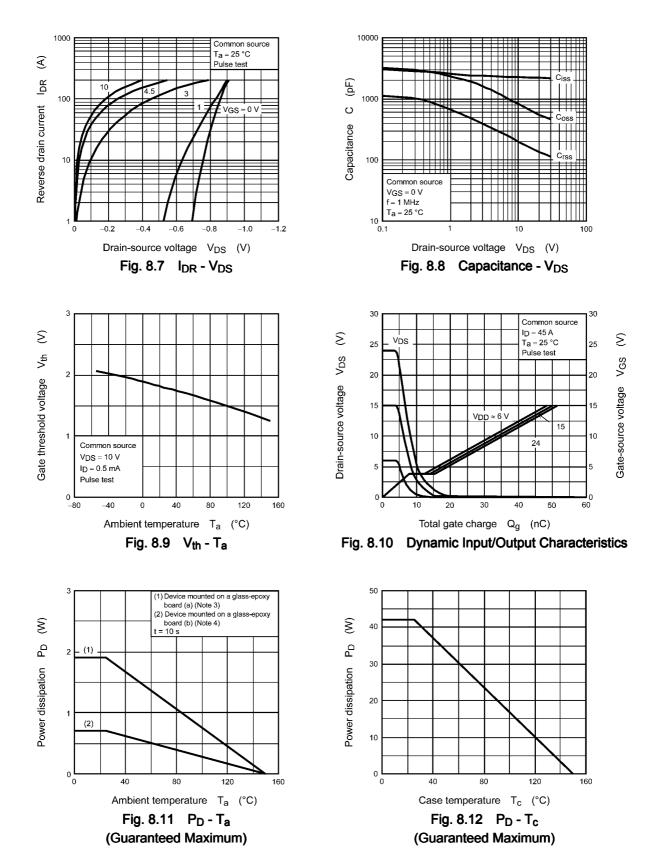
Note 7: Ensure that the channel temperature does not exceed 150 °C.

7. Marking



8. Characteristics Curves (Note)







Ta = 25 °C

increase in

Drain-source voltage V_{DS} (V) Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

VDSS max

100

10

* Single pulse

linearly with

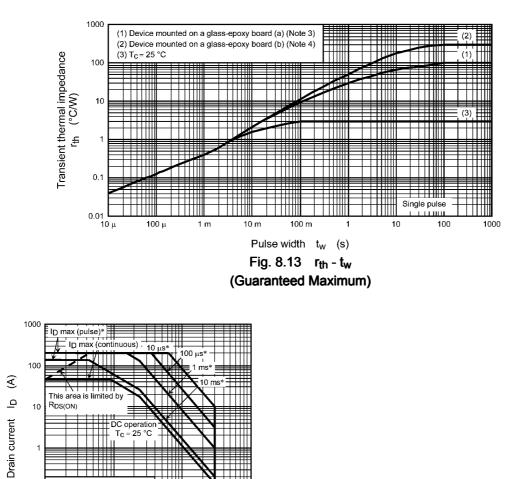
temperature.

Curves must be derated

1

0.1

0.01 L 0.1



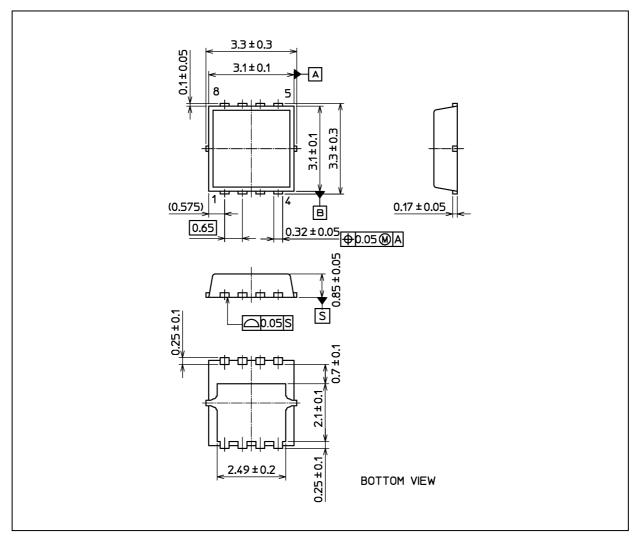
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



TPN2R203NC

Package Dimensions

Unit: mm



Weight: 0.02 g (typ.)

Package Name(s)
TOSHIBA: 2-3X1S
Nickname: TSON Advance

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